Diode Semiconductor Device - Page 1 of 1



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# Inclosure Material:

Glass

**Overall Length:** 

0.300 inches

# Terminal Length:

1.000 inches

# **Overall Diameter:**

0.104 inches

#### End Application:

An/aqs-13b

### Mounting Method:

Terminal

### Features Provided:

Hermetically sealed case

# Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

102.0 regulator voltage

## **Current Rating Per Characteristic:**

4.70 milliamperes peak point current

### **Power Rating Per Characteristic:**

600.0 milliwatts total device dissipation

# Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

# **Test Data Document:**

77068-3185544 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;

excludes any specification, standard or other document that may be referenced in a basic governing drawing)

# Terminal Type And Quantity:

2 uninsulated wire lead

### Shelf Life:

N/a

### Unit Of Measure:

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### Demilitarization:

No

## Fiig:

A110a0